IW4066B

## **Quad Bilateral Switch High-Voltage Silicon-Gate CMOS**

The IW4066B is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. In addition, the on-state resistance is relatively constant over the full input-signal range.

The IW4066B consists of four independent bilateral switches. A single control signal is required per switch. Both the p and the n device in a given switch are biased on or off simultaneously by the control signal. (As show in Fig.1.) The well of the n-channel device on each switch is either tied to the input when the switch is on or to GND when the switch is off. This configuration eliminates the variation of the switch-transistor threshold voltage with input signal, and thus keeps the on-state resistance low over the full operating-signal range.

The advantages over single-channel switches include peak inputsignal voltage swings equal to the full supply voltage, and more constant on-state impedance over the input-signal range.

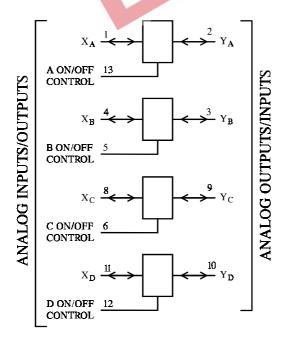
- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):

1.0 V min @ 5.0 V supply

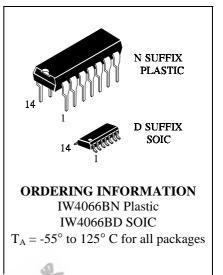
2.0 V min @ 10.0 V supply

2.5 V min @ 15.0 V supply

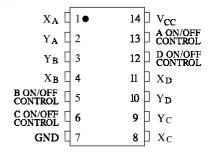
#### **LOGIC DIAGRAM**



 $PIN 14 = V_{CC}$  PIN 7 = GND



#### PIN ASSIGNMENT



#### **FUNCTION TABLE**

On/Off Control Input	State of Analog Switch
L	Off
Н	On



#### MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
$V_{CC}$	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
$V_{IN}$	DC Input Voltage (Referenced to GND)	-0.5 to $V_{CC}$ +0.5	V
$V_{OUT}$	DC Output Voltage (Referenced to GND)	-0.5 to $V_{CC}$ +0.5	V
$I_{IN}$	DC Input Current, per Pin	±10	mA
$P_{\mathrm{D}}$	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
$P_{D}$	Power Dissipation per Output Transistor	100	mW
Tstg	Storage Temperature	-65 to +150	°C
$T_{L}$	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

<sup>\*</sup>Maximum Ratings are those values beyond which damage to the device may occur.

Maximum Rat	Maximum Ratings are those values beyond which damage to the device may occur.						
Functional ope	Functional operation should be restricted to the Recommended Operating Conditions.						
+Derating - Pla	+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C						
SC	SOIC Package: : - 7 mW/°C from 65° to 125°C						
RECOMMI	RECOMMENDED OPERATING CONDITIONS						
Symbol	Parameter Min Max Unit						
V <sub>CC</sub>	V <sub>CC</sub> DC Supply Voltage (Referenced to GND) 3.0 18 V						
$V_{IN}, V_{OUT}$	V <sub>IN</sub> , V <sub>OUT</sub> DC Input Voltage, Output Voltage (Referenced to GND) 0 V <sub>CC</sub> V						
$T_{A}$	T <sub>A</sub> Operating Temperature, All Package Types -55 +125 °C						

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{\rm IN}$  and  $V_{\rm OUT}$  should be constrained to the range GND $\leq$ (V<sub>IN</sub> or V<sub>OUT</sub>) $\leq$ V<sub>CC</sub>.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.



### DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

			$V_{CC}$	Guar	anteed Li	mit	
Symbol	Parameter	Test Conditions	V	≥-55°C	25 °C	≤125 °C	Unit
V <sub>IH</sub>	Minimum High-Level Voltage ON/Off Control Inputs	R <sub>ON</sub> = Per Spec	5.0 10 15		3.5(Min) 7(Min) 11(Min)		V
V <sub>IL</sub>	Minimum Low-Level Voltage ON/Off Control Inputs	R <sub>ON</sub> = Per Spec	5.0 10 15	1 2 2	1 2 2	1 2 2	V
I <sub>IN</sub>	Maximum Input Leakage Current, ON/OFF Control Inputs	$V_{IN} = V_{CC}$ or GND	18	±0.1	±0.1	±1.0	μА
$I_{CC}$	Maximum Quiescent Supply Current (per Package)	$V_{IN} = V_{CC}$ or GND	5.0 10 15 20	0.25 0.5 1 5	0.25 0.5 1 5	7.5 15 30 150	μА
R <sub>ON</sub>	Maximum "ON" Resistance	$V_{\text{C}} = V_{\text{CC}}$ $R_{\text{L}} = 10 \text{ k}\Omega \text{ returned}$ $\text{to } \frac{V_{\text{CC}} - \text{GND}}{2}$ $V_{\text{IS}} = \text{GND to } V_{\text{CC}}$	5.0 10 15	800 310 200	1050 400 240	1300 550 320	Ω
$\Delta R_{ m ON}$	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	$V_{C} = V_{CC}$ $R_{L} = 10 \text{ k}\Omega$	5.0 10 15	- - -	15 10 5		Ω
$I_{ m OFF}$	Maximum Off- Channel Leakage Current, Any One Channel	$egin{array}{l} V_{C} = 0 \ V \\ V_{IS} = 18 \ V; \ V_{OS} = 0 \ V \\ V_{IS} = 0 \ V; \ V_{OS} = 18 V \end{array}$	18	±0.1	±0.1	±1.0	μА
I <sub>ON</sub>	Maximum On- Channel Leakage Current, Any One Channel	V <sub>C</sub> = 0 V V <sub>IS</sub> =18 V; V <sub>OS</sub> = 0 V V <sub>IS</sub> =0 V; V <sub>OS</sub> = 18V	18	±0.1	±0.1	±1.0	μА



#### **AC ELECTRICAL CHARACTERISTICS**( $C_L$ =50pF, $R_L$ =200k $\Omega$ , Input $t_r$ = $t_f$ =20 ns)

		$V_{CC}$	Guaranteed Limit		imit	
Symbol	Parameter	V	≥-55°C	25°C	≤125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Analog Input to	5.0	40	40	80	ns
	Analog Output (Figure 2)	10	20	20	40	
		15	15	15	30	
$t_{PLZ}, t_{PHZ},$	Maximum Propagation Delay, ON/OFF	5.0	70	70	140	ns
$t_{PZL}, t_{PZH}$	Control to Analog Output (Figure 3)	10	40	40	80	
		15	30	30	60	
С	Maximum Capacitance	-				pF
	ON/OFF Control Input			15		_
	Control Input = $\overline{GND}$					
	Analog I/O			7.5		
	Feedthrough			0.6		

# ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

		CO	$V_{CC}$	Limit*	
Symbol	Parameter	Test Conditions	V	25°C	Unit
THD	Total Harmonic Distortion	$V_C = V_{CC}$ , GND = -5 V $R_L = 10 \text{ k}\Omega$ , $f_{IS} = 1 \text{ kHz}$ sine wave	5	0.4	%
BW	Maximum On- Channel Bandwidth or Minimum Frequency Response	$V_C = V_{CC}$ , $GND = -5 \text{ V}$ $R_L = 1 \text{ k}\Omega$		40	MHz
BW	Maximum On- Channel Bandwidth or Minimum Frequency Response	$V_C = GND$ , $V_{IS} = 5$ V $R_L = 1$ k $\Omega$	10	1	MHz
BW	Maximum On- Channel Bandwidth or Minimum Frequency Response	$\begin{aligned} &V_{C}\left(A\right) = V_{CC} = 5 \text{ V} \\ &V_{C}\left(B\right) = GND = -5 \text{ V} \\ &V_{IS}\left(A\right) = 5 \text{ V}_{P-P}, 50 \Omega \text{ source} \\ &R_{L} = 1 k\Omega \end{aligned}$	5	8	MHz
-	Cross talk (Control Input to Signal Output)	$\begin{split} V_{C} &= 10 \text{ V} \\ t_{r},  t_{f} &= 20 \text{ ns} \\ R_{L} &= 10 \text{ k}\Omega \end{split}$	10	50	mV
-	Maximum Control Input Repetition Rate	$\begin{split} &V_{IS} {=} \ V_{CC}, \ R_L = 1 \ k\Omega \\ &C_L = 50 \ pF \\ &V_C {=} \ 10 \ V \ (square \ wave \ centered \ on \ 5 \ V) \\ &t_r, \ t_f = 20 \ ns, \\ &V_{OS} {=} \ 1/2 \ V_{OS} \ \ @1 \ kHz \end{split}$	5 10 15	6 9 9.5	MHz

<sup>\*</sup> Guaranteed limits not tested. Determined by design and verified by qualification.



		Switch Input			Switch (	Output,
		I <sub>IS</sub> (mA)			$V_{OS}$	(V)
$V_{CC}(V)$	$V_{IS}(V)$	-55 °C	+25 °C	+125 °C	Min	Max
5 5	0 5	0.64 -0.64	0.51 -0.51	0.36 -0.36	4.6	0.4
10 10	0 10	1.6 -1.6	1.3 -1.3	0.9 -0.9	- 9.5	0.5
15 15	0 15	4.2 -4.2	3.4 -3.4	2.4 -2.4	13.5	1.5

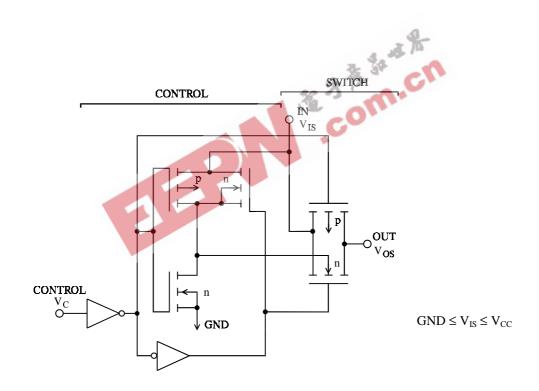


Figure 1. Schematic diagram of 1 of 4 identical switches and its associated control circuitry.

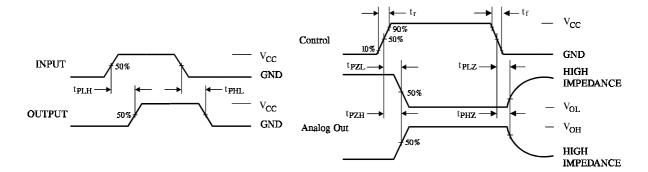
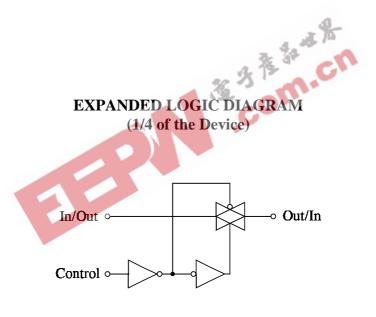


Figure 2. Switching Waveforms

Figure 3. Switching Waveforms



Control	Switch
GND = L	OFF
$V_{CC} = H$	ON